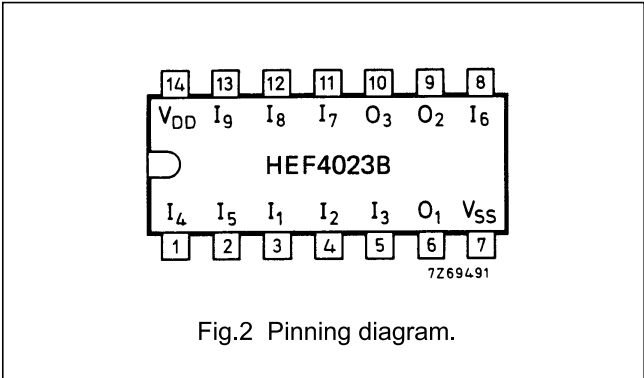
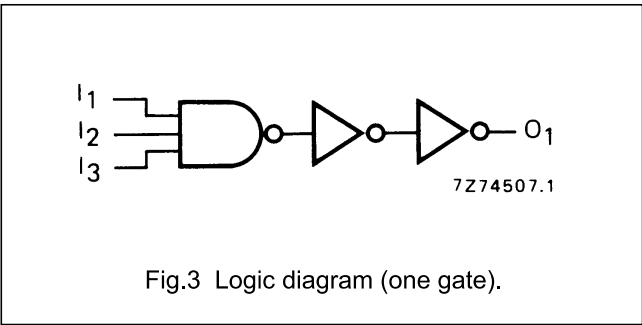
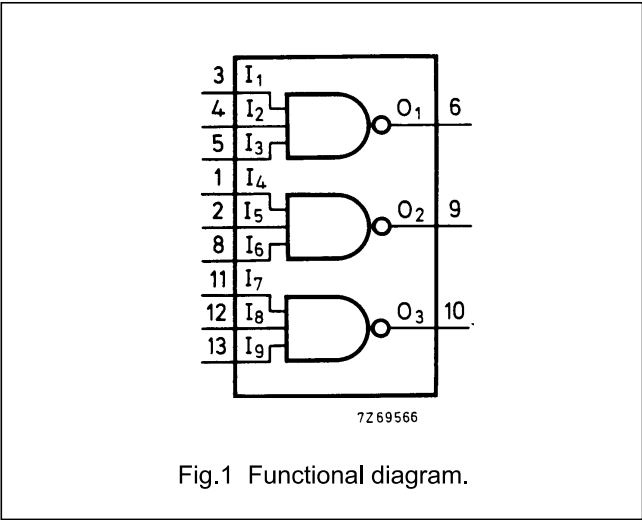


Triple 3-input NAND gate

HEF4023B gates

DESCRIPTION

The HEF4023B provides the positive triple 3-input NAND function. The outputs are fully buffered for highest noise immunity and pattern insensitivity of output impedance.



- HEF4023BP(N): 14-lead DIL; plastic (SOT27-1)
- HEF4023BD(F): 14-lead DIL; ceramic (cerdip) (SOT73)
- HEF4023BT(D): 14-lead SO; plastic (SOT108-1)
- (): Package Designator North America

FAMILY DATA, I_{DD} LIMITS category GATES

See Family Specifications

Triple 3-input NAND gate

HEF4023B
gates**AC CHARACTERISTICS** $V_{SS} = 0\text{ V}$; $T_{amb} = 25\text{ }^{\circ}\text{C}$; $C_L = 50\text{ pF}$; input transition times $\leq 20\text{ ns}$

	V_{DD} V	SYMBOL	TYP.	MAX.		TYPICAL EXTRAPOLATION FORMULA
Propagation delays $I_n \rightarrow O_n$ HIGH to LOW	5	t_{PHL}	65	135	ns	38 ns + (0,55 ns/pF) C_L
	10		25	50	ns	14 ns + (0,23 ns/pF) C_L
	15		15	30	ns	7 ns + (0,16 ns/pF) C_L
	5	t_{PLH}	65	130	ns	38 ns + (0,55 ns/pF) C_L
	10		30	60	ns	19 ns + (0,23 ns/pF) C_L
	15		25	45	ns	17 ns + (0,16 ns/pF) C_L
Output transition times HIGH to LOW	5	t_{THL}	60	120	ns	10 ns + (1,0 ns/pF) C_L
	10		30	60	ns	9 ns + (0,42 ns/pF) C_L
	15		20	40	ns	6 ns + (0,28 ns/pF) C_L
	5	t_{TLH}	60	120	ns	10 ns + (1,0 ns/pF) C_L
	10		30	60	ns	9 ns + (0,42 ns/pF) C_L
	15		20	40	ns	6 ns + (0,28 ns/pF) C_L

	V_{DD} V	TYPICAL FORMULA FOR P (μW)	
Dynamic power dissipation per package (P)	5	$1200 f_i + \sum (f_o C_L) \times V_{DD}^2$	where f_i = input freq. (MHz) f_o = output freq. (MHz) C_L = load capacitance (pF) $\sum (f_o C_L)$ = sum of outputs V_{DD} = supply voltage (V)
	10	$5500 f_i + \sum (f_o C_L) \times V_{DD}^2$	
	15	$16\,400 f_i + \sum (f_o C_L) \times V_{DD}^2$	